NPN Epitaxial Planar Silicon Transistor



CPH6222

DC / DC Converter Applications

Applications

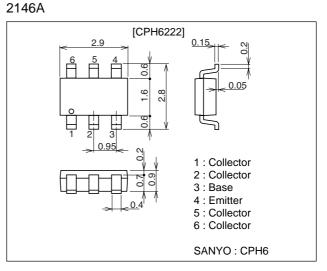
• Relay drivers, lamp drivers, motor drivers, strobe.

Features

- Adoption of MBIT process.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall package facilitates miniaturization in end products (mounting height : 0.9mm).
- High allowable power dissipation.

Package Dimensions

unit : mm



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		40	V
Collector-to-Emitter Voltage	VCEO		30	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		3	А
Collector Current (Pulse)	ICP		5	А
Base Current	IB		600	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² X0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Unit
Collector Cutoff Current	ICBO	VCB=30V, IE=0			0.1	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0			0.1	μA
DC Current Gain	hFE	V _{CE} =2V, I _C =500mA	200		560	
Gain-Bandwidth Product	fΤ	VCE=10V, IC=500mA		420		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		20		pF
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Marking : CW

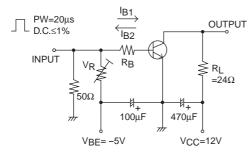
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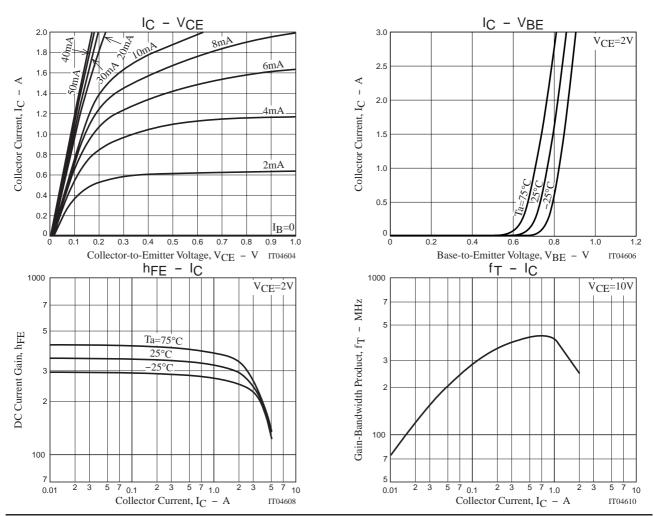
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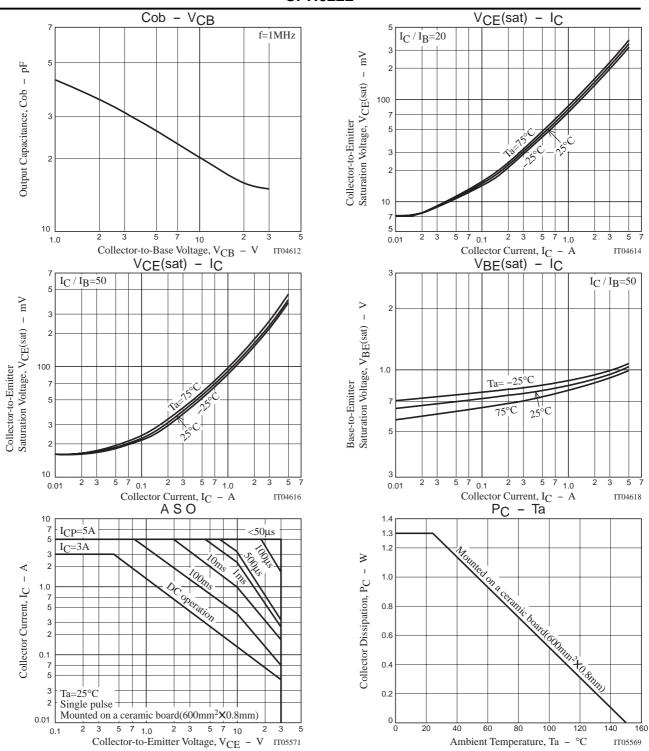
Parameter	Symbol	Conditions	Ratings			1.1
			min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)1	IC=1.5A, IB=30mA		130	195	mV
	V _{CE} (sat)2	IC=1.5A, IB=75mA		120	180	mV
Base-to-Emitter Saturation Voltage	VBE(sat)	IC=1.5A, IB=30mA		0.83	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0	40			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	30			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=10μA, IC=0	5			V
Turn-ON Time	ton	See specified Test Circuit.		30		ns
Storage Time	tstg	See specified Test Circuit.		300		ns
Fall Time	tf	See specified Test Circuit.		25		ns

Switching Time Test Circuit



 $I_C=20I_{B1}=-20I_{B2}=500mA$





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